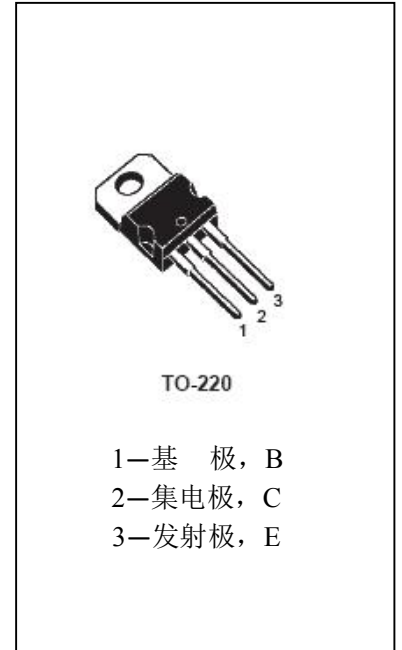


## ■ 主要用途

功率放大，电视机伴音及帧输出(与C2073互补)

## ■ 外形图及引脚排列



## ■ 极限值 (Ta=25℃)

Tstg—贮存温度.....	-55~150℃
Tj—结温.....	150℃
PC—集电极功率耗散 (Ta=25℃) .....	1.5W
PC—集电极功率耗散 (Tc=25℃) .....	25W
VCBO—集电极—基极电压.....	-150V
VCEO—集电极—发射极电压.....	-150V
VEBO—发射极—基极电压.....	-5V
IC—集电极电流.....	-1.2A
IB—基极电流.....	-0.5A

## ■ 电参数 (Ta=25℃)

参数符号	符 号 说 明	最小值	典型值	最大值	单 位	测 试 条 件
BVCBO	集电极—基极击穿电压	150			V	IC=100μA, IE=0
BVCEO	集电极—发射极击穿电压	150			V	IC=10mA, IB=0
BVEBO	发射极—基极击穿电压	5			V	IE=1mA, IC=0
ICBO	集电极—基极截止电流			-10	μA	V <sub>CB</sub> =-120V, IE=0
IEBO	发射极—基极截止电流			-10	μA	V <sub>EB</sub> =-5V, IC=0
h <sub>FE</sub>	直流电流增益	100		210		V <sub>CE</sub> =-5V, IC=-500mA
V <sub>CE(sat)</sub>	集电极—发射极饱和电压			-1.5	V	IC=-1A, IB=-100mA
f <sub>T</sub>	特征频率		4		MHz	V <sub>CE</sub> =-10V, IC=-500mA
C <sub>ob</sub>	共基极输出电容		55		pF	V <sub>CB</sub> =-10V, IE=0, f=1MHz

**NOTE:**

1. Exceeding the maximum ratings of the device in performance may cause damage to the device, even the permanent failure, which may affect the dependability of the machine. Please do not exceed the absolute maximum ratings of the device when circuit designing.
2. When installing the heat sink, please pay attention to the torsional moment and the smoothness of the heat sink.
3. MOSFETs is the device which is sensitive to the static electricity, it is necessary to protect the device from being damaged by the static electricity when using it.
4. Shenzhen Minos reserves the right to make changes in this specification sheet and is subject to change without prior notice.

**CONTACT:****深圳市迈诺斯科技有限公司（总部）**

地址：深圳市福田区华富街道田面社区深南中路4026号田面城市大厦22B-22C

邮编：518025

电话：0755-83273777